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<u>Vishay Semiconductor/Diodes Division</u> <u>SB15H45-E3/73</u>

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Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of SB15H45-E3/73 - DIODE SCHOTTKY 45V 7A DO204AL

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SB15H45

Vishay General Semiconductor

Photovoltaic Solar Cell Protection Schottky Plastic Rectifier

High Barrier Technology for Improved High Temperature Performance This datasheet reflects specifications of product in actual application.

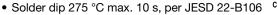


P600

PRIMARY CHARACTERISTICS				
I _{F(AV)}	15 A			
V_{RRM}	45 V			
I _{FSM}	300 A			
V _F at I _F = 15 A	0.46 V			
T _{OP} max.	175 °C			
T _J max. (DC forward current)	200 °C			
Package	P600			
Diode variation	Single die			

FEATURES

- Guardring for overvoltage protection
- · Low forward voltage drop, low power losses
- High efficiency operation
- High forward surge capability



• Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: P600, molded epoxy over passivated junction Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)			
PARAMETER	SYMBOL	SB15H45	UNIT
Maximum repetitive peak reverse voltage	V _{RRM}	45	V
NA	I _{F(AV)} (1)	15	
Maximum average forward rectified current (fig. 1)	I _{F(AV)} (2)	7	A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	300	А
Operating junction and storage temperature range	nction and storage temperature range T _{OP} , T _{STG}		°C
Junction temperature in DC forward current without reverse bias, $t \le 1 h$ (fig. 1)	T _J ⁽³⁾	≤ 200	°C

Notes

- $^{(1)}$ With heatsink, $T_L = 25$ °C
- (2) Without heatsink, free air
- (3) Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage	I _F = 5 A		~	0.48	-	V	
	I _F = 7.5 A	T _A = 25 °C		0.50	-		
	I _F = 15 A			0.56	0.64		
	I _F = 5 A	T _A = 125 °C	T _A = 125 °C	V _F ⁽¹⁾	0.35	-	V
	I _F = 7.5 A				0.39	-	
	I _F = 15 A			0.46	0.54		
Reverse current	V _R = 45 V	T _A = 25 °C T _A = 125 °C	I _R ⁽²⁾	10	300	μΑ	
	v _R = 45 V		IR (=)	8	20	mA	
Typical junction capacitance	4.0 V, 1 MHz		CJ	1020	-	pF	

Notes

⁽²⁾ Pulse test: 10 ms pulse width

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	SB15H45	UNIT	
Thermal resistance	R _{0JA} (1)	66	°C/W	
Thermal resistance	R _{0JL} (1)	14	C/ VV	
Typical thermal resistance	R ₀ JL (2)	3.5	°C/W	

Notes

 $^{^{(2)}}$ T_A = 75 °C, T_L = 125 °C, T_J = 175 °C, infinite mass at 0.375" (9.5 mm) lead length

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g) PREFERRED PACKAGE CODE BASE QUANTITY		BASE QUANTITY	DELIVERY MODE		
SB15H45-E3/54	1.756	54	800	13" diameter paper tape and reel		

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

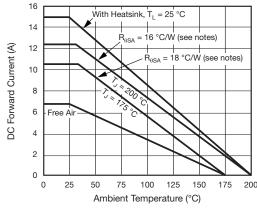


Fig. 1 - Forward Current Derating Curve

Notes

- Mounted on junction box
- Using DC forward current
- Junction box SA (sink to ambient)
- Assumes $R_{\theta LS}$ (lead to sink) of 5 °C/W
- Thermal resistance $R_{\theta SA}$ (sink to ambient):

$$R_{\theta SA} = \frac{(T_J - T_A)}{P_D} - (R_{\theta JL} + R_{\theta LS})$$

P_D: Power dissipation P_D = V_F x I_F

 $^{^{(1)}}$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽¹⁾ Without heatsink, free air



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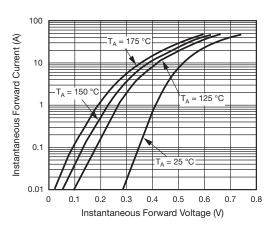


Fig. 2 - Typical Instantaneous Forward Characteristics

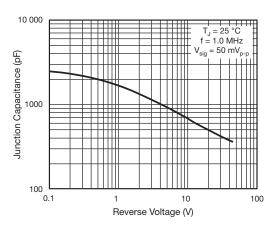


Fig. 4 - Typical Junction Capacitance

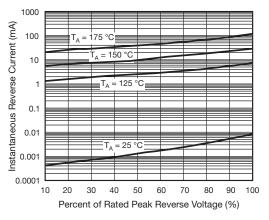
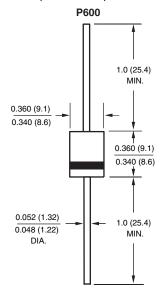


Fig. 3 - Typical Reverse Characteristics

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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